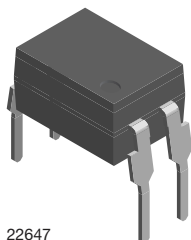
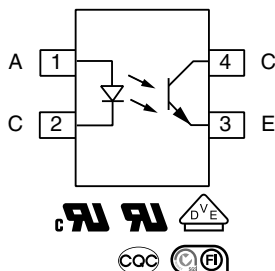


# Low Input Current Optocoupler, Phototransistor Output, High Reliability, 5300 V<sub>RMS</sub>



22647



## DESCRIPTION

The 110 °C rated VO615C series feature a high current transfer ratio, low coupling capacitance and high isolation voltage. These couplers have a GaAs infrared diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a plastic DIP-4 package.

The coupling devices are designed for signal transmission between two electrically separated circuits.

## FEATURES

- Copper lead-frame
- Operating temperature from -55 °C to +110 °C
- Isolation test voltage, 5300 V<sub>RMS</sub>
- High collector emitter voltage, V<sub>CEO</sub> = 80 V
- Low saturation voltage
- Fast switching times
- Low CTR degradation
- Low coupling capacitance
- End stackable, 0.100" (2.54 mm) spacing
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## APPLICATIONS

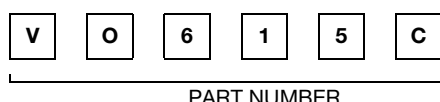
- AC adapters
- SMPS
- PLC
- Factory automation
- Game consoles

## AGENCY APPROVALS

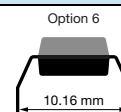
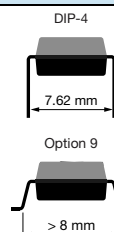
The safety application model number covering all products in this datasheet is VO615C. This model number should be used when consulting safety agency documents.

- UL1577, file no. E52744
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-5 (VDE 0884), available with option 1
- FIMKO EN60065 and EN60950-1, file no. FI 27409
- CQC GB8898-2001

## ORDERING INFORMATION


CTR  
BIN

PACKAGE OPTION

TAPE  
AND  
REEL


| AGENCY CERTIFIED/PACKAGE            | CTR (%)  |                                                 |              |              |
|-------------------------------------|----------|-------------------------------------------------|--------------|--------------|
|                                     | 10 mA    |                                                 |              |              |
| UL, cUL, FIMKO, CQC                 | 40 to 80 | 63 to 125                                       | 100 to 200   | 160 to 320   |
| DIP-4                               | VO615C-1 | -                                               | -            | -            |
| VDE, UL, cUL, FIMKO, CQC (option 1) | 40 to 80 | 63 to 125                                       | 100 to 200   | 160 to 320   |
| DIP-4, 400 mil, option 6            | -        | VO615C-2X016                                    | VO615C-3X016 | VO615C-4X016 |
| SMD-4, option 9                     | -        | VO615C-2X019T,<br>VO615C-2X019T1 <sup>(1)</sup> | -            | -            |

## Notes

- Additional options may be available, please contact the sales office.

<sup>(1)</sup> T1 rotation in tape and reel packaging.

| <b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                    |            |             |                    |
|--------------------------------------------------------------------------------------------------------|------------------------------------|------------|-------------|--------------------|
| PARAMETER                                                                                              | TEST CONDITION                     | SYMBOL     | VALUE       | UNIT               |
| <b>INPUT</b>                                                                                           |                                    |            |             |                    |
| Reverse voltage                                                                                        |                                    | $V_R$      | 6           | V                  |
| Forward current                                                                                        |                                    | $I_F$      | 60          | mA                 |
| Forward surge current                                                                                  | $t_p \leq 10\text{ }\mu\text{s}$   | $I_{FSM}$  | 1.5         | A                  |
| Power dissipation                                                                                      | at $25\text{ }^{\circ}\text{C}$    | $P_{diss}$ | 70          | mW                 |
| <b>OUTPUT</b>                                                                                          |                                    |            |             |                    |
| Collector emitter voltage                                                                              |                                    | $V_{CEO}$  | 80          | V                  |
| Emitter collector voltage                                                                              |                                    | $V_{ECO}$  | 7           | V                  |
| Collector current                                                                                      |                                    | $I_C$      | 50          | mA                 |
|                                                                                                        | $t_p \leq 1\text{ ms}$             |            | 100         | mA                 |
| Output power dissipation                                                                               | at $25\text{ }^{\circ}\text{C}$    | $P_{diss}$ | 150         | mW                 |
| <b>COUPLER</b>                                                                                         |                                    |            |             |                    |
| Isolation test voltage (RMS)                                                                           | $t = 1\text{ min}$                 | $V_{ISO}$  | 5300        | $V_{RMS}$          |
| Total power dissipation                                                                                |                                    | $P_{tot}$  | 200         | mW                 |
| Operation temperature                                                                                  |                                    | $T_{amb}$  | -55 to +110 | $^{\circ}\text{C}$ |
| Storage temperature range                                                                              |                                    | $T_{stg}$  | -55 to +150 | $^{\circ}\text{C}$ |
| Junction temperature                                                                                   |                                    | $T_j$      | 125         | $^{\circ}\text{C}$ |
| Soldering temperature <sup>(1)</sup>                                                                   | 2 mm from case, $\leq 10\text{ s}$ | $T_{sld}$  | 260         | $^{\circ}\text{C}$ |

**Notes**

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- <sup>(1)</sup> Refer to reflow profile for soldering conditions for surface mounted devices (SMD), and wave profile for soldering conditions for through hole devices (DIP), please go to "Assembly Instructions" ([www.vishay.com/doc?80054](http://www.vishay.com/doc?80054)).

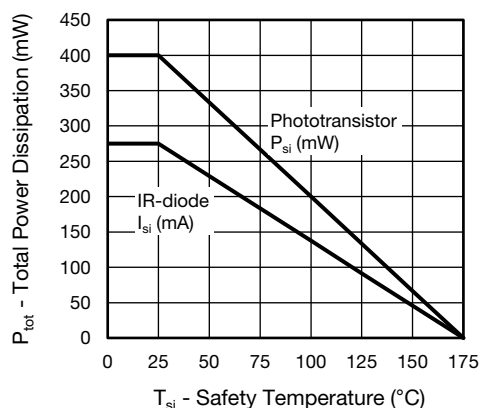


Fig. 1 - Total Power Dissipation vs. Safety Temperature

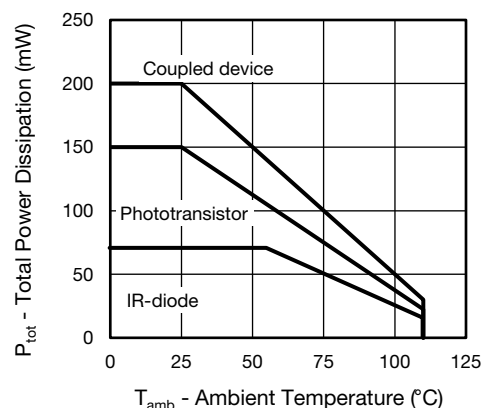


Fig. 2 - Total Power Dissipation vs. Ambient Temperature

| <b>ELECTRICAL CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                          |             |      |      |      |               |
|----------------------------------------------------------------------------------------------------------|--------------------------------------------------------------------------|-------------|------|------|------|---------------|
| PARAMETER                                                                                                | TEST CONDITION                                                           | SYMBOL      | MIN. | TYP. | MAX. | UNIT          |
| <b>INPUT</b>                                                                                             |                                                                          |             |      |      |      |               |
| Forward voltage                                                                                          | $I_F = 60\text{ mA}$                                                     | $V_F$       |      | 1.35 | 1.6  | V             |
| Reverse current                                                                                          | $V_R = 6\text{ V}$                                                       | $I_R$       |      | 0.01 | 10   | $\mu\text{A}$ |
| Junction capacitance                                                                                     | $V_R = 0\text{ V}$ , $f = 1\text{ MHz}$                                  | $C_j$       |      | 9    |      | pF            |
| <b>OUTPUT</b>                                                                                            |                                                                          |             |      |      |      |               |
| Collector emitter leakage current                                                                        | $V_{CE} = 10\text{ V}$                                                   | $I_{CEO}$   |      | 0.3  | 100  | nA            |
| Collector emitter capacitance                                                                            | $V_{CE} = 5\text{ V}$ , $f = 1\text{ MHz}$                               | $C_{CE}$    |      | 2.8  |      | pF            |
| Collector emitter breakdown voltage                                                                      | $I_C = 1\text{ mA}$                                                      | $BV_{CEO}$  | 80   |      |      | V             |
| Emitter collector breakdown voltage                                                                      | $I_E = 100\text{ }\mu\text{A}$                                           | $BV_{ECO}$  | 7    |      |      | V             |
| <b>COUPLER</b>                                                                                           |                                                                          |             |      |      |      |               |
| Collector emitter saturation voltage                                                                     | $I_F = 10\text{ mA}$ , $I_C = 2.5\text{ mA}$                             | $V_{CEsat}$ |      | 0.25 | 0.4  | V             |
| Coupling capacitance                                                                                     | $f = 1\text{ MHz}$                                                       | $C_C$       |      | 0.4  |      | pF            |
| Cut-off frequency                                                                                        | $I_F = 10\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\text{ }\Omega$ | $f_{ctr}$   |      | 110  |      | kHz           |

**Note**

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

| <b>CURRENT TRANSFER RATIO</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                              |          |        |      |      |      |      |
|------------------------------------------------------------------------------------------------------|----------------------------------------------|----------|--------|------|------|------|------|
| PARAMETER                                                                                            | TEST CONDITION                               | PART     | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| $I_C/I_F$                                                                                            | $I_F = 10\text{ mA}$ , $V_{CE} = 5\text{ V}$ | VO615C-1 | CTR    | 40   |      | 80   | %    |
|                                                                                                      |                                              | VO615C-2 | CTR    | 63   |      | 125  | %    |
|                                                                                                      |                                              | VO615C-3 | CTR    | 100  |      | 200  | %    |
|                                                                                                      |                                              | VO615C-4 | CTR    | 160  |      | 320  | %    |

| <b>SWITCHING CHARACTERISTICS</b> ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified) |                                                                         |           |      |      |      |               |
|---------------------------------------------------------------------------------------------------------|-------------------------------------------------------------------------|-----------|------|------|------|---------------|
| PARAMETER                                                                                               | TEST CONDITION                                                          | SYMBOL    | MIN. | TYP. | MAX. | UNIT          |
| <b>NON-SATURATED</b>                                                                                    |                                                                         |           |      |      |      |               |
| Rise time                                                                                               | $I_C = 2\text{ mA}$ , $V_{CC} = 5\text{ V}$ , $R_L = 100\text{ }\Omega$ | $t_r$     |      | 3    |      | $\mu\text{s}$ |
| Fall time                                                                                               |                                                                         | $t_f$     |      | 3    |      | $\mu\text{s}$ |
| Turn-on time                                                                                            |                                                                         | $t_{on}$  |      | 6    |      | $\mu\text{s}$ |
| Turn-off time                                                                                           |                                                                         | $t_{off}$ |      | 4    |      | $\mu\text{s}$ |

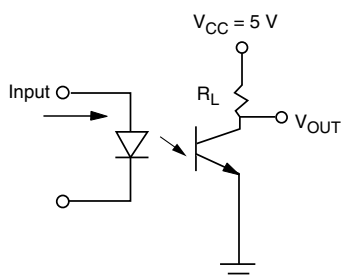


Fig. 3 - Test Circuit

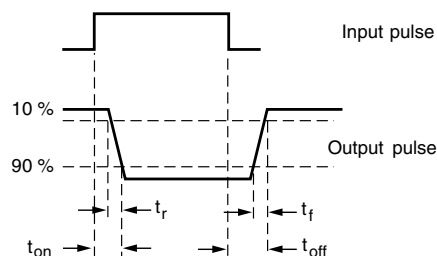


Fig. 4 - Test Circuit and Waveforms

| SAFETY AND INSULATION RATINGS                                |                                                  |                  |                |            |
|--------------------------------------------------------------|--------------------------------------------------|------------------|----------------|------------|
| PARAMETER                                                    |                                                  | SYMBOL           | VALUE          | UNIT       |
| MAXIMUM SAFETY RATINGS                                       |                                                  |                  |                |            |
| Output safety power                                          |                                                  | $P_{SO}$         | 700            | mW         |
| Input safety current                                         |                                                  | $I_{si}$         | 400            | mW         |
| Safety temperature                                           |                                                  | $T_S$            | 175            | °C         |
| Comparative tracking index                                   |                                                  | CTI              | 175            |            |
| INSULATION RATED PARAMETERS                                  |                                                  |                  |                |            |
| Maximum withstanding isolation voltage                       |                                                  | $V_{ISO}$        | 5300           | $V_{RMS}$  |
| Maximum transient isolation voltage                          |                                                  | $V_{IOTM}$       | 8000           | $V_{peak}$ |
| Maximum repetitive peak isolation voltage                    |                                                  | $V_{IORM}$       | 565            | $V_{peak}$ |
|                                                              |                                                  | $V_{IORM}^{(1)}$ | 1140           | $V_{peak}$ |
| Insulation resistance                                        | $T_{amb} = 25\text{ °C}, V_{DC} = 500\text{ V}$  | $R_{IO}$         | $\geq 10^{12}$ | $\Omega$   |
| Isolation resistance                                         | $T_{amb} = 100\text{ °C}, V_{DC} = 500\text{ V}$ | $R_{IO}$         | $\geq 10^{11}$ | $\Omega$   |
| Climatic classification (according to IEC 68 part 1)         |                                                  |                  | 55/110/21      |            |
| Environment (pollution degree in accordance to DIN VDE 0109) |                                                  |                  | 2              |            |
| Internal and external creepage                               | Standard DIP-4                                   |                  | $\geq 7$       | mm         |
|                                                              | 400 mil DIP-4                                    |                  | $\geq 8$       | mm         |
| Clearance                                                    | Standard DIP-4                                   |                  | $\geq 7$       | mm         |
|                                                              | 400 mil DIP-4                                    |                  | $\geq 8$       | mm         |
| Insulation thickness                                         |                                                  |                  | 0.4            | mm         |

**Notes**

- As per DIN EN 60747-5-5, 2, § 7.4.3.8.2, this optocoupler is suitable for “safe electrical insulation” only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.

<sup>(1)</sup> Only for option 6.

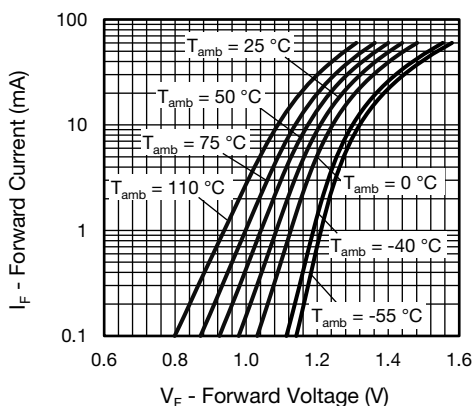
**TYPICAL CHARACTERISTICS** ( $T_{amb} = 25\text{ °C}$ , unless otherwise specified)


Fig. 5 - Forward Voltage vs. Forward Current

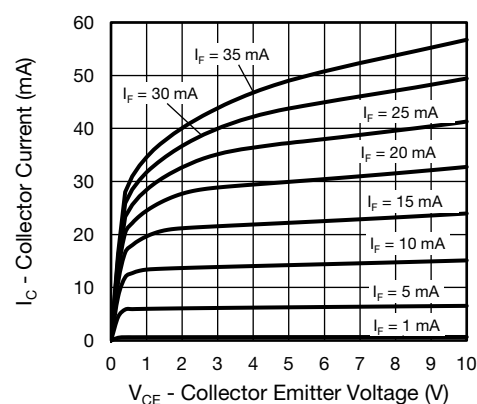


Fig. 6 - Collector Current vs. Collector Emitter Voltage (NS)

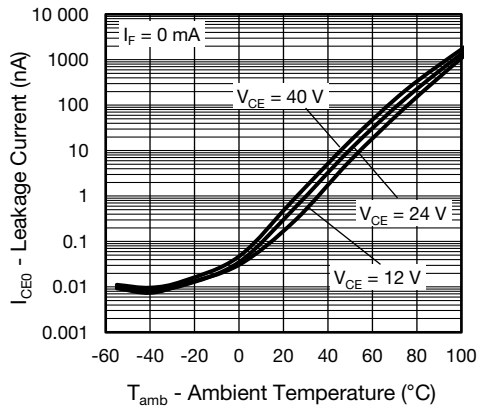


Fig. 7 - Leakage Current vs. Ambient Temperature

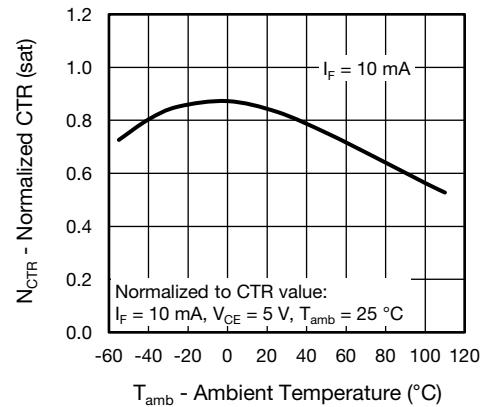


Fig. 10 - Normalized Current Transfer Ratio (saturated) vs. Ambient Temperature

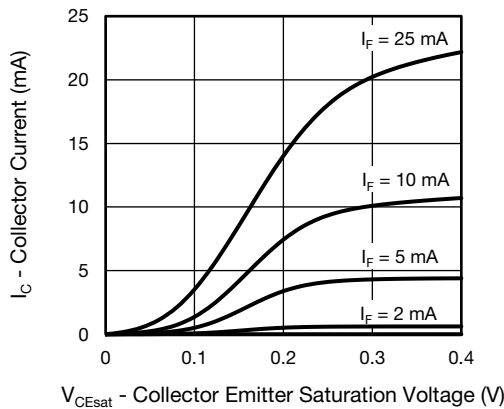


Fig. 8 - Collector Current vs. Collector Emitter Voltage (saturated)

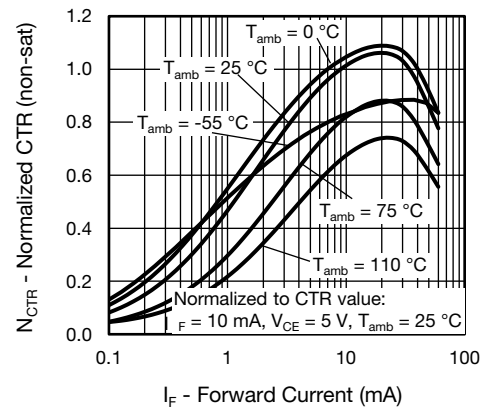


Fig. 11 - Normalized CTR (non-saturated) vs. Forward Current

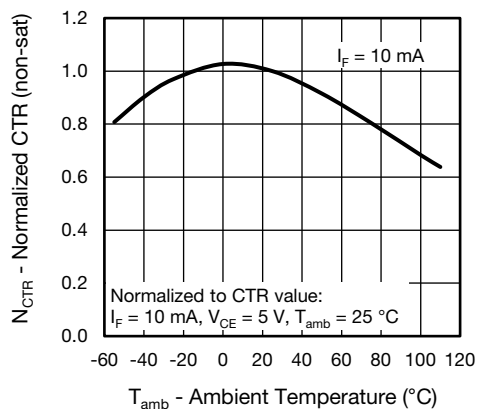


Fig. 9 - Normalized Current Transfer Ratio (non-saturated) vs. Ambient Temperature

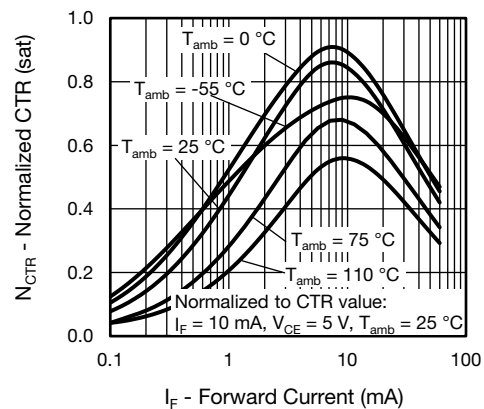


Fig. 12 - Normalized CTR (saturated) vs. Forward Current

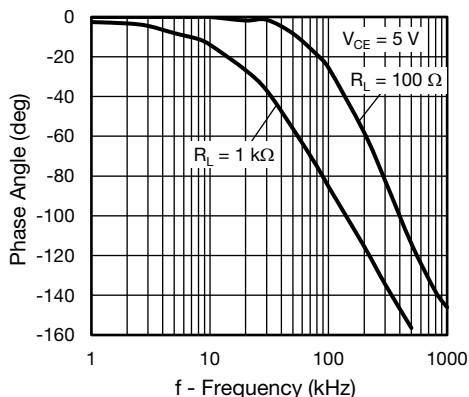


Fig. 13 - Phase Angle vs. Frequency

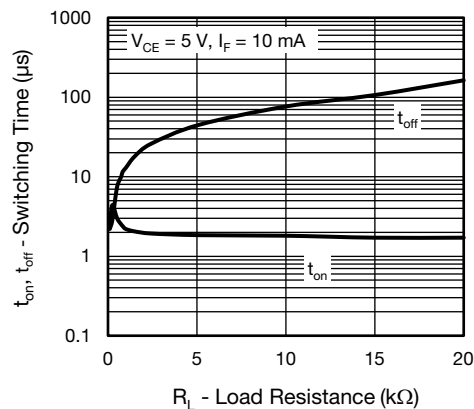


Fig. 15 - Switching Time vs. Load Resistance

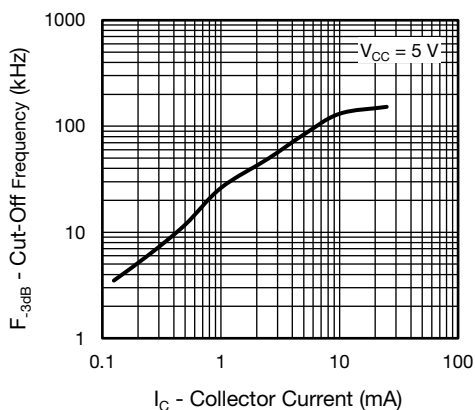


Fig. 14 - Frequency vs. Collector Current

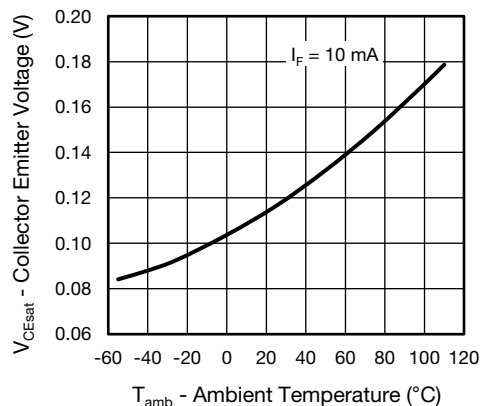
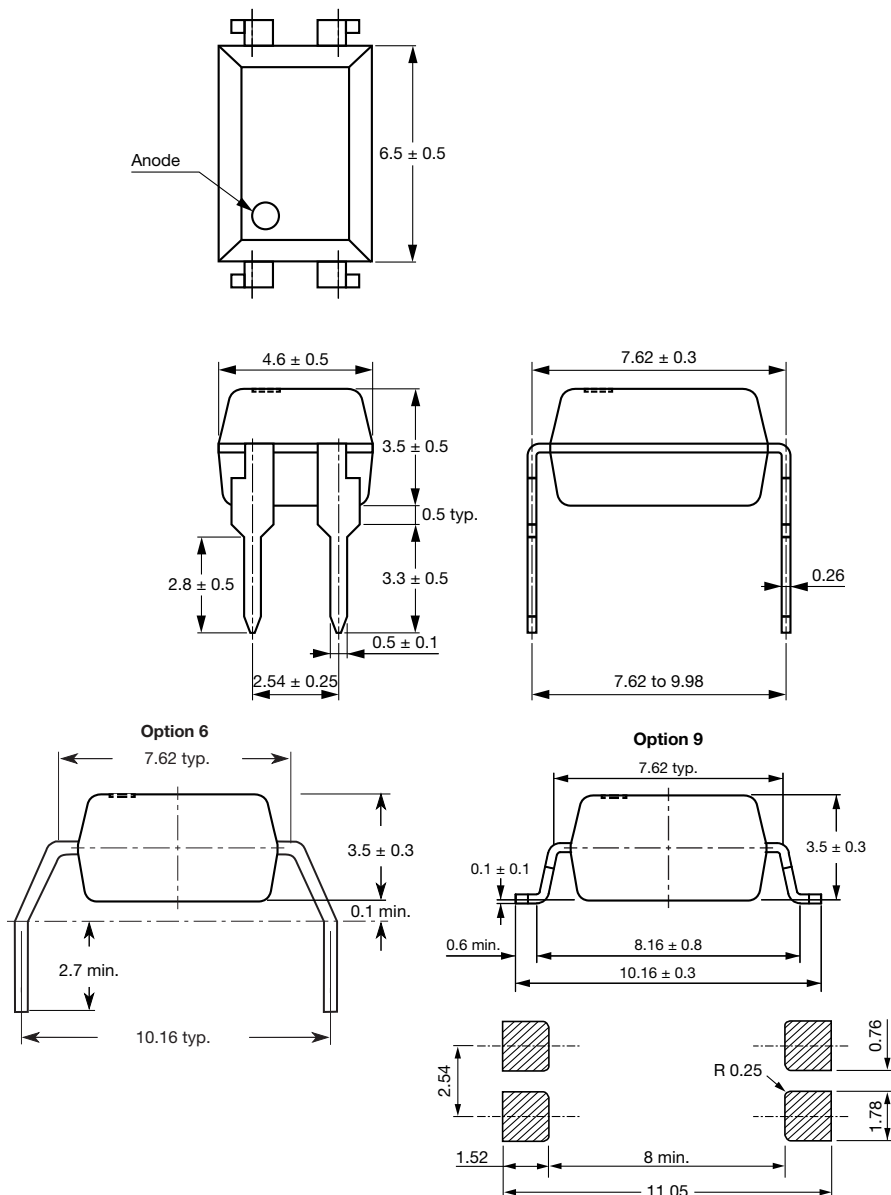
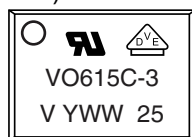


Fig. 16 - Collector Emitter Voltage vs. Ambient Temperature (saturated)

**PACKAGE DIMENSIONS** in millimeters

**PACKAGE MARKING** (Example of VO615C-3X016)

**Note**

- Option information is not marked.

**PACKING INFORMATION**

| DEVICE PER TUBE |            |           |           |
|-----------------|------------|-----------|-----------|
| TYPE            | UNITS/TUBE | TUBES/BOX | UNITS/BOX |
| DIP-4           | 100        | 40        | 4000      |

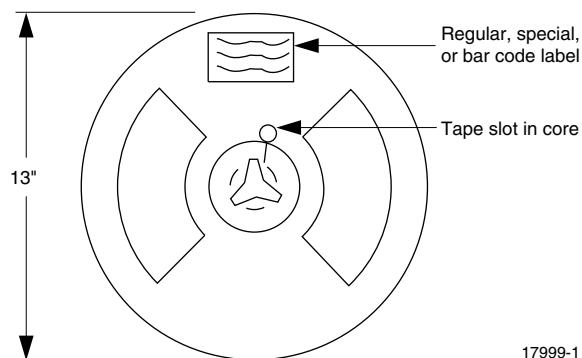


Fig. 17 - Tape and Reel Shipping Medium

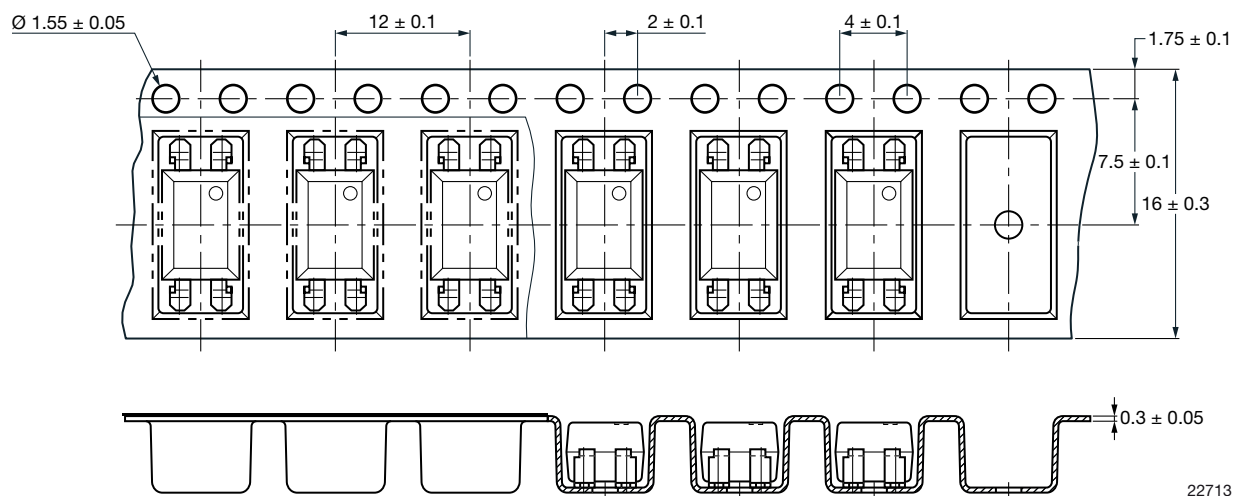


Fig. 18 - Tape Packing for Option 7 and 9, T1 rotation (2000 units per reel)



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**Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.**

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- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
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- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.